## Features

- $128 \mathrm{~K} \times 36,256 \mathrm{~K} \times 18$ memory configurations
- Supports fast access times:

Commercial:

- 7.5ns up to 117 MHz clock frequency
- $\overline{\text { LBO }}$ input selects interleaved or linear burst mode
- Self-timed write cycle with global write control ( $\overline{\mathrm{GW}}$ ), byte write enable ( $\overline{\mathrm{BWE}}$ ), and byte writes ( $\overline{\mathrm{BW}} \mathrm{x}$ )
- 3.3 V core power supply
- Power down controlled by ZZ input
- 3.3V I/O
- Optional - Boundary Scan JTAG Interface (IEEE 1149.1 compliant)
- Packaged in a JEDEC Standard 100 -pin plastic thin quad flatpack (TQFP),


## Description

TheAS8C403625/1825 are high-speed SRAMs organized as $128 \mathrm{~K} \times 36 / 256 \mathrm{~K} \times 18$. The AS8C403625/1825 SRAMs contain write, data, address and control registers. There are no registers in the data output path (flow-through architecture). Internal logic allows the SRAM to generate a self-timed write based upon a decision which can be left until the end of the write cycle.

The burstmode feature offers the highestlevel of performance to the system designer, as the AS8C403625/1825 can provide four cycles of data for a single address presented to the SRAM. An internal burst address counter accepts the firstcycle address from the processor, initiating the access sequence. The firstcycle of outputdata will flow-through from the array aftera clock-to-data access time delay from the rising clock edge of the same cycle. If burst mode operation is selected ( $\overline{\mathrm{ADV}}=\mathrm{LOW}$ ), the subsequent three cycles of output data will be available to the user on the next three rising clock edges. The order of these three addresses are defined by the internal burst counter and the $\overline{\mathrm{LBO}}$ input pin.

The AS8C403625/1825 SRAMs utilize IDT's latest high-performance CMOS process and are packaged in a JEDEC standard $14 \mathrm{~mm} \times 20 \mathrm{~mm}$ 100-pinthin plastic quad flatpack (TQFP)

Pin Description Summary

| A0-A17 | Address Inputs | Input | Synchronous |
| :---: | :---: | :---: | :---: |
| $\bar{C} \bar{E}$ | Chip Enable | Input | Synchronous |
| CSo, $\overline{\mathrm{C}} \mathrm{S}_{1}$ | Chip Selects | Input | Synchronous |
| $\overline{O E}$ | Output Enable | Input | Asynchronous |
| $\overline{\text { GW }}$ | Global Write Enable | Input | Synchronous |
| $\overline{\text { BWE }}$ | Byte Write Enable | Input | Synchronous |
| $\overline{\mathrm{BW}}_{1}, \overline{\mathrm{BW}}_{2}, \overline{\mathrm{BW}}_{3}, \overline{\mathrm{BW}}_{4}{ }^{(1)}$ | Individual Byte Write Selects | Input | Synchronous |
| CLK | Clock | Input | N/A |
| $\overline{\text { ADV }}$ | Burst Address Advance | Input | Synchronous |
| $\overline{\text { ADSC }}$ | Address Status (Cache Controller) | Input | Synchronous |
| $\overline{\text { ADS } \bar{P}}$ | Address Status (Processor) | Input | Synchronous |
| $\overline{\text { LBO }}$ | Linear / Interleaved Burst Order | Input | DC |
| TMS | Test Mode Select | Input | Synchronous |
| TDI | Test Data Input | Input | Synchronous |
| TCK | Test Clock | Input | N/A |
| TDO | Test Data Output | Output | Synchronous |
| $\overline{\text { TRST }}$ | JTAG Reset (Optional) | Input | Asynchronous |
| Z | Sleep Mode | Input | Asynchronous |
| //O--//O31, //Op 1-//Op4 | Data Input / Output | 1/0 | Synchronous |
| VDd, VdDQ | Core Power, I/O Power | Supply | N/A |
| Vss | Ground | Supply | N/A |
| NOTE: |  |  |  |

Pin Definitions ${ }^{(1)}$

| Symbol | Pin Function | 1/0 | Active | Description |
| :---: | :---: | :---: | :---: | :---: |
| A0-A17 | Address Inputs | 1 | N/A | Synchronous Address inputs. The address register is triggered by a combi-nation of the rising edge of CLK and $\overline{\text { ADSC }}$ Low or $\overline{\text { DSP }}$ Low and $\overline{\mathrm{C}}$ Low. |
| $\overline{\text { ADSC }}$ | Address Status (Cache Controller) | 1 | LOW | Synchronous Address Status from Cache Controller. $\overline{\text { ADSC }}$ is an active LOW input that is used to load the address registers with new addresses. |
| $\overline{\text { ADSP }}$ | Address Status (Processor) | 1 | LOW | Synchronous Address Status from Processor. $\overline{\text { ADSP }}$ is an active LOW input that is used to load the address registers with new addresses. $\overline{\text { ADSP }}$ is gated by $\overline{\mathrm{CE}}$. |
| $\overline{\text { ADV }}$ | Burst Address Advance | 1 | LOW | Synchronous Address Advance. $\overline{\mathrm{ADV}}$ is an active LOW input that is used to advance the internal burst counter, controlling burst access atter the initial address is loaded. When the input is HIGH the burst counter is not incremented; that is, there is no address advance. |
| $\overline{\text { BWE }}$ | Byte Write Enable | 1 | LOW | Synchronous byte write enable gates the byte write inputs $\overline{\mathrm{BW}} 1-\overline{\mathrm{BW}} 4$. If $\overline{\mathrm{BWE}}$ is LOW at the rising edge of CLK then $\overline{\mathrm{BW}} \mathrm{x}$ inputs are passed to the next stage in the circuit. If $\overline{\mathrm{BWE}}$ is HIGH then the byte write inputs are blocked and only $\overline{G W}$ can initiate a write cycle. |
| $\overline{\mathrm{BW}} 1-\overline{\mathrm{BW}} 4$ | Individual Byte Write Enables | 1 | LOW |  wite causes all outputs to be disabled. |
| $\overline{\mathrm{CE}}$ | Chip Enable | 1 | LOW | Synchronous chip enable. $\overline{\mathrm{C}} \overline{\mathrm{E}}$ is used with CS 0 and $\overline{\mathrm{C}} \overline{1}_{1}$ to enable AS8C403625/1825. $\overline{\mathrm{C}}$ also gates $\overline{\mathrm{A} S P} \overline{\text { P }}$. |
| CLK | Clock | 1 | N/A | This is the clock input. All timing references for the device are made with respect to this input. |
| CSo | Chip Select 0 | 1 | HIGH | Synchronous active HIGH chip select. CS 0 is used with $\overline{\mathrm{C}}$ E and $\overline{\mathrm{S}} \overline{\mathrm{S}}_{1}$ to enable the chip. |
| $\overline{\mathrm{C}} \overline{1}_{1}$ | Chip Select 1 | 1 | LOW | Synchronous active LOW chip select. $\bar{C} \bar{S}_{1}$ is used with $\overline{\mathrm{C}}$ E and CS 0 to enable the chip. |
| $\overline{\text { GW }}$ | Global Write Enable | 1 | LOW | Synchronous global write enable. This input will write all four 9-bit data bytes when LOW on the rising edge of CLK. $\overline{\text { GW }}$ supersedes individual byte write enables. |
| $\begin{aligned} & \text { //O--//O31 } \\ & \text { //OP1-//OP4 } \end{aligned}$ | Data Input/Output | I/O | N/A | Synchronous data input/output (//O) pins. The data input path is registered, triggered by the rising edge of CLK. The data output path is flow-through (no output register). |
| $\overline{\text { LBO }}$ | Linear Burst Order | 1 | LOW | Asynchronous burst order selection input. When $\overline{\mathrm{LBO}}$ is HIGH, the inter-leaved burst sequence is selected. When $\overline{\text { LBO }}$ is LOW the Linear burst sequence is selected. $\overline{\mathrm{LBO}}$ is a static input and must not change state while the device is operating. |
| $\overline{\mathrm{OE}}$ | Ouput Enable | 1 | LOW | Asynchronous output enable. When $\overline{O E}$ is LOW the data output drivers are enabled on the $/ O$ pins if the chip is also selected. When $\overline{\mathrm{OE}}$ is HIGH the I/O pins are in a high-impedance state. |
| TMS | Test ModeSelect | 1 | N/A | Gives input command for TAP controller. Sampled on rising edge of TDK. This pin has an internal pullup. |
| TDI | Test Data Input | 1 | N/A | Serial input of registers placed between TDI and TDO. Sampled on rising edge of TCK. This pin has an internal pullup. |
| TCK | Test Clock | 1 | N/A | Clock input of TAP controller. Each TAP event is clocked. Test inputs are captured on rising edge of TCK, while test outputs are driven from the falling edge of TCK. This pin has an internal pullup. |
| TDO | Test DataOutput | 0 | N/A | Serial output of registers placed between TDI and TDO. This output is active depending on the state of the TAP controller. |
| TRST | JTAG Reset (Optional) | 1 | LOW | Optional Asynchronous JTAG reset. Can be used to reset the TAP controller, but not required. JTAG reset occurs automatically at power up and also resets using TMS and TCK per IEEE 1149.1. If not used TRST can be left floating. This pin has an internal pullup. Only available in BGA package. |
| Z | Sleep Mode | 1 | HIGH | Asynchronous sleep mode input. ZZ HIGH will gate the CLK internally and power down theAS8C403625/1825 to its lowest power consumption level. Data retention is guaranteed in Sleep Mode.This pin has an internal pull down. |
| VDD | Power Supply | N/A | N/A | 3.3 V core power supply. |
| VDDQ | Power Supply | N/A | N/A | 3.3V I/O Supply. |
| Vss | Ground | N/A | N/A | Ground. |
| NC | No Connect | N/A | N/A | NC pins are not electrically connected to the device. |

## NOTE:

1. All synchronous inputs must meet specified setup and hold times with respect to CLK.

## Functional Block Diagram



## Absolute Maximum Ratings ${ }^{(1)}$

| Symbol | Rating |  <br> Industrial Values | Unit |
| :--- | :--- | :---: | :---: |
| VTERM $^{(2)}$ | Terminal Voltage with <br> Respect to GND | -0.5 to +4.6 | V |
| VTERM $^{(3,6)}$ | Terminal Voltage with <br> Respect to GND | -0.5 to VDD | V |
| VTERM $^{(4,6)}$ | Terminal Voltage with <br> Respect to GND | -0.5 to VDD +0.5 | V |
| VTERM $^{(5,6)}$ | Terminal Voltage with <br> Respect to GND | -0.5 to VDDQ +0.5 | V |
| TA $^{(7)}$ | Commercial <br> Operating Temperature | -0 to +70 | ${ }^{\circ} \mathrm{C}$ |
|  | Industrial <br> Operating Temperature | -40 to +85 | ${ }^{\circ} \mathrm{C}$ |
|  | Temperature <br> Under Bias | -55 to +125 | ${ }^{\circ} \mathrm{C}$ |
| TSTG | Storage <br> Temperature | -55 to +125 | ${ }^{\circ} \mathrm{C}$ |
| PT | Power Dissipation | 2.0 | W |
| IOUT | DC Output Current | 50 | mA |

NOTES:
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1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
2. VDD terminals only.
3. VdDQ terminals only.
4. Input terminals only.
5. I/O terminals only.
6. This is a steady-state DC parameter that applies after the power supplies have ramped up. Power supply sequencing is not necessary; however, the voltage on any input or I/O pin cannot exceed VdDQ during power supply ramp up.
7. TA is the "instant on" case temperature.

## 100 Pin TQFP Capacitance

(TA = +25 ${ }^{\circ} \mathrm{C}, \mathrm{f}=1.0 \mathrm{mhz}$ )

| Symbol | Parameter $^{(1)}$ | Conditions | Max. | Unit |
| :---: | :--- | :--- | :---: | :---: |
| CIN | Input Capacitance | $\mathrm{VIN}=3 \mathrm{dV}$ | 5 | pF |
| C/o | I/O Capacitance | Vout $=3 \mathrm{dV}$ | 7 | pF |

## Recommended Operating Temperature Supply Voltage

| Grade | Temperature $^{(1)}$ | Vss | VdD | VdDQ |
| :---: | :---: | :---: | :---: | :---: |
| Commercial | $0^{\circ} \mathrm{C}$ to $+70^{\circ} \mathrm{C}$ | 0 V | $3.3 \mathrm{~V} \pm 5 \%$ | $3.3 \mathrm{~V} \pm 5 \%$ |
| Industrial | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | 0 V | $3.3 \mathrm{~V} \pm 5 \%$ | $3.3 \mathrm{~V} \pm 5 \%$ |

NOTES:
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1. TA is the "instant on" case temperature.

## Recommended DC Operating Conditions

| Symbol | Parameter | Min. | Typ. | Max. | Unit |
| :---: | :--- | :---: | :---: | :---: | :---: |
| VDD | Core Supply Voltage | 3.135 | 3.3 | 3.465 | V |
| VDDQ | I/O Supply Voltage | 3.135 | 3.3 | 3.465 | V |
| VSS | Supply Voltage | 0 | 0 | 0 | V |
| VIH | Input High Voltage - Inputs | 2.0 | - | VDD +0.3 | V |
| VIH | Input High Voltage - I/O | 2.0 | - | VDDQ $+0.3^{(1)}$ | V |
| VIL | Input Low Voltage | $-0.3^{(2)}$ | - | 0.8 | V |

NOTES:
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1. $\mathrm{V}_{\mathrm{IH}}(\max )=\mathrm{VDDQ}+1.0 \mathrm{~V}$ for pulse width less than tcYC/2, once per cycle.
2. $\mathrm{V}_{\mathrm{IL}}(\min )=-1.0 \mathrm{~V}$ for pulse width less than $\mathrm{tcYc} / 2$, once per cycle.

119 BGA Capacitance
( $\mathrm{TA}_{\mathrm{A}}=+25^{\circ} \mathrm{C}, \mathrm{f}=1.0 \mathrm{mhz}$ )

| Symbol | Parameter ${ }^{(1)}$ | Conditions | Max | Unit |
| :---: | :--- | :---: | :---: | :---: |
| CIN | Input Capacitance | $\mathrm{VIN}=3 \mathrm{dV}$ | 7 | pF |
| CVo | I/O Capacitance | Vout $=3 \mathrm{dV}$ | 7 | pF |

165 fBGA Capacitance
( $\mathrm{TA}=+25^{\circ} \mathrm{C}, \mathrm{f}=1.0 \mathrm{mhz}$ )

| Symbol | Parameter $^{(1)}$ | Conditions | Max. | Unit |
| :---: | :--- | :---: | :---: | :---: |
| CIN | Input Capacitance | $\mathrm{VIN}=3 \mathrm{dV}$ | 7 | pF |
| $\mathrm{C} / \mathrm{o}$ | I/O Capacitance | Vout $=3 \mathrm{dV}$ | 7 | pF |

NOTE:

1. This parameter is guaranteed by device characterization, but not production tested.

## Pin Configuration - 128K x 36



## 100 TQFP <br> Top View

## NOTES:

1. Pin 14 does not have to be directly connected to Vss as long as the input voltage is $\leq$ VIL.
2. Pin 64 can be left unconnected and the device will always remain in active mode.

## Pin Configuration - 256K x 18



NOTES:

1. Pin 14 does not have to be directly connected to Vss as long as the input voltage is $\leq$ VIL.
2. Pin 64 can be left unconnected and the device will always remain in active mode.

DC Electrical Characteristics Over the Operating
Temperature and Supply Voltage Range ( $\mathrm{VdD}=3.3 \mathrm{~V} \pm 5 \%$ )

| Symbol | Parameter | Test Conditions | Min. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| \||Lإ | Input Leakage Current | Vdd $=$ Max., $\mathrm{V} \mathbb{N}=0 \mathrm{~V}$ to VdD | - | 5 | $\mu \mathrm{A}$ |
| \||L|| | ZZ , $\overline{\text { LBO }}$ and JTAG Input Leakage Current ${ }^{(1)}$ | Vdd = Max., V IN $=0 \mathrm{~V}$ to VdD | - | 30 | $\mu \mathrm{A}$ |
| IILOI | Output Leakage Current | Vout $=0 \mathrm{~V}$ to VDDQ, Device Deselected | - | 5 | $\mu \mathrm{A}$ |
| Vol | Output Low Voltage | $\mathrm{lOL}=+8 \mathrm{~mA}, \mathrm{VDD}=\mathrm{Min}$. | - | 0.4 | V |
| VOH | Output High Voltage | $\mathrm{IOH}=-8 \mathrm{~mA}, \mathrm{VDD}=\mathrm{Min}$. | 2.4 | - | V |

NOTE:

1. The $\overline{\mathrm{LBO}}, \mathrm{TMS}, \mathrm{TDI}$, TCK and $\overline{\text { TRST }}$ pins will be internally pulled to VDD and the $Z Z$ in will be internally pulled to Vss if they are not actively driven in the application.

## DC Electrical Characteristics Over the Operating Temperature and Supply Voltage Range ${ }^{(1)}$

| Symbol | Parameter | Test Conditions | 7.5ns | 8ns |  | 8.5ns |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | Com'I Only | Com'l | Ind | Com'l | Ind |  |
| IDD | Operating Power Supply Current | Device Selected, Outputs Open, VdD = Max., VDDQ $=$ Max., $V I N \geq$ VIH or $\leq V I L, f=f m a x^{(2)}$ | 255 | 200 | 210 | 180 | 190 | mA |
| ISB1 | CMOS Standby Power Supply Current | Device Deselected, Outputs Open, Vdd = Max., VDDQ $=$ Max., $\mathrm{VIN}^{2} \geq$ VHD or $\leq \operatorname{VLD}, \mathrm{f}=0^{(2,3)}$ | 30 | 30 | 35 | 30 | 35 | mA |
| IsB2 | Clock Running Power Supply Current | Device Deselected, Outputs Open, VDD = Max., $V_{D D Q}=\text { Max., VIN } \geq \text { VHD or } \leq \operatorname{VLD}, f=f m a x ~(2,3)$ | 90 | 85 | 95 | 80 | 90 | mA |
| Izz | Full Sleep Mode Supply Current | $Z \mathrm{Z} \geq \mathrm{VHD}, \mathrm{V} D \mathrm{D}=$ Max. | 30 | 30 | 35 | 30 | 35 | mA |

NOTES:

1. All values are maximum guaranteed values.
2. At $f=f$ fmax, inputs are cycling at the maximum frequency of read cycles of 1 tccyc while $\overline{\operatorname{ADSC}}=\mathrm{LOW} ; \mathrm{f}=0$ means no input lines are changing.


## AC Test Conditions

(VdDQ = 3.3V)

| Input Pulse Levels | 0 to 3 V |
| :--- | :---: |
| Input Rise/Fall Times | 2 ns |
| Input Timing Reference Levels | 1.5 V |
| Output Timing Reference Levels | 1.5 V |
| AC Test Load | See Figure 1 |

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## AC Test Load



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Figure 2. Lumped Capacitive Load, Typical Derating

Synchronous Truth Table ${ }^{(1,3)}$

| Operation | Address Used | $\overline{\mathrm{C}} \mathrm{E}$ | $\mathrm{CS}_{0}$ | $\overline{\mathrm{C}} \mathrm{S}_{1}$ | $\overline{\text { ADSP }}$ | $\overline{\text { ADSC }}$ | $\overline{\text { ADV }}$ | $\overline{\mathrm{GW}}$ | $\overline{\text { BWE }}$ | $\overline{\mathrm{BW}} \mathrm{x}$ | $\overline{\mathrm{O}}{ }^{(2)}$ | CLK | 1/0 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Deselected Cycle, Power Down | None | H | X | X | X | L | X | X | X | X | X | $\uparrow$ | H-Z |
| Deselected Cycle, Power Down | None | L | X | H | L | X | X | X | X | X | X | $\uparrow$ | H-Z |
| Deselected Cycle, Power Down | None | L | L | X | L | X | x | X | x | X | x | $\uparrow$ | H-Z |
| Deselected Cycle, Power Down | None | L | X | H | X | L | X | X | X | X | X | $\uparrow$ | H-Z |
| Deselected Cycle, Power Down | None | L | L | X | X | L | X | X | X | X | X | $\uparrow$ | H-Z |
| Read Cycle, Begin Burst | External | L | H | L | L | X | X | X | X | X | L | $\uparrow$ | Dout |
| Read Cycle, Begin Burst | External | L | H | L | L | X | X | X | X | X | H | $\uparrow$ | H-Z |
| Read Cycle, Begin Burst | External | L | H | L | H | L | X | H | H | X | L | $\uparrow$ | Dout |
| Read Cycle, Begin Burst | External | L | H | L | H | L | X | H | L | H | L | $\uparrow$ | Dout |
| Read Cycle, Begin Burst | External | L | H | L | H | L | X | H | L | H | H | $\uparrow$ | H-Z |
| Write Cycle, Begin Burst | External | L | H | L | H | L | X | H | L | L | X | $\uparrow$ | Din |
| Write Cycle, Begin Burst | External | L | H | L | H | L | X | L | X | X | X | $\uparrow$ | Din |
| Read Cycle, Continue Burst | Next | X | X | X | H | H | L | H | H | X | L | $\uparrow$ | Dout |
| Read Cycle, Continue Burst | Next | X | X | X | H | H | L | H | H | X | H | $\uparrow$ | H-Z |
| Read Cycle, Continue Burst | Next | X | X | X | H | H | L | H | X | H | L | $\uparrow$ | Dout |
| Read Cycle, Continue Burst | Next | X | X | X | H | H | L | H | X | H | H | $\uparrow$ | H-Z |
| Read Cycle, Continue Burst | Next | H | X | X | X | H | L | H | H | X | L | $\uparrow$ | Dout |
| Read Cycle, Continue Burst | Next | H | X | X | X | H | L | H | H | X | H | $\uparrow$ | H-Z |
| Read Cycle, Continue Burst | Next | H | X | X | X | H | L | H | X | H | L | $\uparrow$ | Dout |
| Read Cycle, Continue Burst | Next | H | X | X | X | H | L | H | X | H | H | $\uparrow$ | H-Z |
| Write Cycle, Continue Burst | Next | X | X | X | H | H | L | H | L | L | X | $\uparrow$ | DiN |
| Write Cycle, Continue Burst | Next | X | X | X | H | H | L | L | X | X | X | $\uparrow$ | Din |
| Write Cycle, Continue Burst | Next | H | X | X | X | H | L | H | L | L | X | $\uparrow$ | Din |
| Write Cycle, Continue Burst | Next | H | X | X | X | H | L | L | X | X | X | $\uparrow$ | Din |
| Read Cycle, Suspend Burst | Current | X | X | X | H | H | H | H | H | X | L | $\uparrow$ | Dout |
| Read Cycle, Suspend Burst | Current | X | X | X | H | H | H | H | H | X | H | $\uparrow$ | H-Z |
| Read Cycle, Suspend Burst | Current | X | X | X | H | H | H | H | X | H | L | $\uparrow$ | Dout |
| Read Cycle, Suspend Burst | Current | X | X | X | H | H | H | H | X | H | H | $\uparrow$ | H-Z |
| Read Cycle, Suspend Burst | Current | H | X | X | X | H | H | H | H | X | L | $\uparrow$ | Dout |
| Read Cycle, Suspend Burst | Current | H | X | X | X | H | H | H | H | X | H | $\uparrow$ | H-Z |
| Read Cycle, Suspend Burst | Current | H | X | X | X | H | H | H | X | H | L | $\uparrow$ | Dout |
| Read Cycle, Suspend Burst | Current | H | X | X | X | H | H | H | X | H | H | $\uparrow$ | H-Z |
| Write Cycle, Suspend Burst | Current | X | X | X | H | H | H | H | L | L | X | $\uparrow$ | Din |
| Write Cycle, Suspend Burst | Current | X | X | X | H | H | H | L | X | X | X | $\uparrow$ | Din |
| Write Cycle, Suspend Burst | Current | H | X | x | X | H | H | H | L | L | X | $\uparrow$ | Din |
| Write Cycle, Suspend Burst | Current | H | X | X | X | H | H | L | X | X | X | $\uparrow$ | Din |

## NOTES:

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1. $\mathrm{L}=\mathrm{VIL}, \mathrm{H}=\mathrm{V}$ IH, $\mathrm{X}=$ Don't Care.
2. $\overline{\mathrm{OE}}$ is an asynchronous input.
3. ZZ - low for the table.

Synchronous Write Function Truth Table ${ }^{(1,2)}$

| Operation | $\overline{\mathrm{GW}}$ | $\overline{\text { BWE }}$ | $\overline{\mathrm{BW}}_{1}$ | $\overline{\mathrm{BW}} 2$ | $\overline{\mathrm{BW}} 3$ | $\overline{\mathrm{BW}} 4$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Read | H | H | X | X | X | X |
| Read | H | L | H | H | H | H |
| Write all Bytes | L | X | X | X | X | X |
| Write all Bytes | H | L | L | L | L | L |
| Write Byte $1^{(3)}$ | H | L | L | H | H | H |
| Write Byte $2^{(3)}$ | H | L | H | L | H | H |
| Write Byte $3^{(3)}$ | H | L | H | H | L | H |
| Write Byte $4^{(3)}$ | H | L | H | H | H | L |

NOTES:

1. $L=V$ IL, $H=V_{I H}, X=$ Don't Care.
2. $\overline{\mathrm{BW}}_{3}$ and $\overline{\mathrm{BW}}_{4}$ are not applicable for the AS8C401825.
3. Multiple bytes may be selected during the same cycle.

## Asynchronous Truth Table ${ }^{(1)}$

| Operation $^{(2)}$ | $\overline{\mathrm{OE}}$ | $\mathbf{Z}$ | I/O Status | Power |
| :---: | :---: | :---: | :---: | :---: |
| Read | L | L | Data Out | Active |
| Read | H | L | High-Z | Active |
| Write | X | L | Hective |  |
| Deselected | X | L | Standby |  |
| Sleep Mode | H | High-Z | Sleep |  |

NOTES:

1. $\mathrm{L}=\mathrm{V}_{\mathrm{IL}}, \mathrm{H}=\mathrm{V}_{\mathrm{H}}, \mathrm{X}=$ Don't Care.
2. Synchronous function pins must be biased appropriately to satisfy operation requirements.

## Interleaved Burst Sequence Table ( $\overline{\mathrm{LBO}}=\mathrm{VdD}$ )

|  | Sequence 1 |  | Sequence 2 |  | Sequence 3 |  | Sequence 4 |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | A1 | A0 | A1 | A0 | A1 | A0 | A1 | A0 |
| First Address | 0 | 0 | 0 | 1 | 1 | 0 | 1 | 1 |
| Second Address | 0 | 1 | 0 | 0 | 1 | 1 | 1 | 0 |
| Third Address | 1 | 0 | 1 | 1 | 0 | 0 | 0 | 1 |
| Fourth Address ${ }^{(1)}$ | 1 | 1 | 1 | 0 | 0 | 1 | 0 | 0 |

NOTE:
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1. Upon completion of the Burst sequence the counter wraps around to its initial state.

## Linear Burst Sequence Table ( $\overline{\mathrm{LBO}}=\mathrm{Vss}$ )

|  | Sequence 1 |  | Sequence 2 |  | Sequence 3 |  | Sequence 4 |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | A1 | A0 | A1 | A0 | A1 | A0 | A1 | A0 |
| First Address | 0 | 0 | 0 | 1 | 1 | 0 | 1 | 1 |
| Second Address | 0 | 1 | 1 | 0 | 1 | 1 | 0 | 0 |
| Third Address | 1 | 0 | 1 | 1 | 0 | 0 | 0 | 1 |
| Fourth Address ${ }^{(1)}$ | 1 | 1 | 0 | 0 | 0 | 1 | 1 | 0 |

NOTE:

1. Upon completion of the Burst sequence the counter wraps around to its initial state.

AC Electrical Characteristics
(Vdd = 3.3V $\pm 5 \%$, Commercial and Industrial Temperature Ranges)

| Symbol | Parameter | $7.5 \mathrm{~s}^{(5)}$ |  | 8 ns |  | 8.5 ns |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min. | Max. | Min. | Max. | Min. | Max. | Unit |

## Clock Parameter

| tcrc | Clock Cycle Time | 8.5 | - | 10 | - | 11.5 | - | ns |
| :--- | :--- | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| tch ${ }^{(1)}$ | Clock High Pulse Width | 3 | - | 4 | - | 4.5 | - | ns |
| tcc $^{(1)}$ | Clock Low Pulse Width | 3 | - | 4 | - | 4.5 | - | ns |

## Output Parameters

| tcD | Clock High to Valid Data | - | 7.5 | - | 8 | - | 8.5 | ns |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| tcDC | Clock High to Data Change | 2 | - | 2 | - | 2 | - | ns |
| ta $\mathrm{z}^{(2)}$ | Clock High to Ouput Active | 0 | - | 0 | - | 0 | - | ns |
| tCHz $Z^{2}$ ) | Clock High to Data High-Z | 2 | 3.5 | 2 | 3.5 | 2 | 3.5 | ns |
| toe | Output Enable Access Time | - | 3.5 | - | 3.5 | - | 3.5 | ns |
| to $\mathrm{Z}^{(2)}$ | Output Enable Low to Output Active | 0 | - | 0 | - | 0 | - | ns |
| torz ${ }^{(2)}$ | Output Enable High to Output High-Z | - | 3.5 | - | 3.5 | - | 3.5 | ns |

## Set Up Times

| tsA | Address Setup Time | 1.5 | - | 2 | - | 2 | - | ns |
| :--- | :--- | :---: | :--- | :--- | :--- | :--- | :--- | :--- |
| tss | Address Status Setup Time | 1.5 | - | 2 | - | 2 | - | ns |
| tsD | Data In Setup Time | 1.5 | - | 2 | - | 2 | - | ns |
| tsw | Write Setup Time | 1.5 | - | 2 | - | 2 | - | ns |
| tsAV | Address Advance Setup Time | 1.5 | - | 2 | - | 2 | - | ns |
| tsc | Chip Enable/Select Setup Time | 1.5 | - | 2 | - | 2 | - | ns |

## Hold Times

| tha | Address Hold Time | 0.5 | - | 0.5 | - | 0.5 | - | ns |
| :--- | :--- | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| ths | Address Status Hold Time | 0.5 | - | 0.5 | - | 0.5 | - | ns |
| thD | Data In Hold Time | 0.5 | - | 0.5 | - | 0.5 | - | ns |
| thw | Write Hold Time | 0.5 | - | 0.5 | - | 0.5 | - | ns |
| thav | Address Advance Hold Time | 0.5 | - | 0.5 | - | 0.5 | - | ns |
| tHC | Chip Enable/Select Hold Time | 0.5 | - | 0.5 | - | 0.5 | - | ns |

## Sleep Mode and Configuration Parameters

| tZPW | ZZ Pulse Width | 100 | - | 100 | - | 100 |
| :--- | :--- | :--- | :--- | :--- | :--- | :---: |
| tZR $^{(3)}$ | ZZ Recovery Time | 100 | - | 100 | - | 100 |
| tcFG ${ }^{(4)}$ | Configuration Set-up Time | - | ns |  |  |  |

## NOTES:

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1. Measured as HIGH above VIH and LOW below VIL.
2. Transition is measured $\pm 200 \mathrm{mV}$ from steady-state.
3. Device must be deselected when powered-up from sleep mode.
4. tCFG is the minimum time required to configure the device based on the $\overline{\mathrm{LBO}}$ input. $\overline{\mathrm{LBO}}$ is a static input and must not change during normal operation.
5. Commercial temperature range only.

Timing Waveform of Flow-Through Read Cycle ${ }^{(1,2)}$


1. O1 (Ax) represents the first output from the external address $A x$. O1 (Ay) represents the first output from the external address Ay; O2 (Ay) represents the next output data in the burst sequence of the base address $A y$, etc. where $A 0$ and $A 1$ are advancing for the four word burst in the sequence defined by the state of the $\overline{\mathrm{LBO}}$ input. 2. ZZ input is LOW and $\overline{\mathrm{LBO}}$ is Don't Care for this cycle.

Timing Waveform of Combined Flow-Through Read and Write Cycles ${ }^{(1,2,3)}$

NOTES:

1. Device is selected through entire cycle; $\overline{\mathrm{C}} \overline{\mathrm{E}}$ and $\overline{\mathrm{CS}} 1$ are LOW, CSO is HIGH. 2. ZZ input is LOW and $\overline{\mathrm{LBO}}$ is Don't Care for this cycle.
2. $O 1(A x)$ representsthe first outputfrom the external address $A x$. $11(A y)$ representsthefirstinputfrom the externaladdress $A y ; O 1(A z)$ representsthefirstoutputfrom the external address $A z ; O 2(A z)$ represents
the next output data in the burst sequence of the base address $A z$, etc. where $A 0$ and $A 1$ are advancing for the four word burst in the sequence defined by the state of the $\overline{L B O}$ input.

Timing Waveform of Write Cycle No. 1 - $\overline{\text { GW }}$ Controlled ${ }^{(1,2,3)}$


NOTES:
. ZZ input is LOW, $\overline{B W E}$ is HIGH and $\overline{\mathrm{BB}} \overline{\mathrm{O}}$ is Don't Care for this cycle. O4 (Aw) represents the final output data in the burst sequence of the base address Aw. 11 (Ax) represents the first input from the external address Ax. I1 (Ay) represents the first input from the external $\frac{\text { address Ay; I2 (Ay) represents the next input data in the burst sequence of the base address Ay, etc. where } A 0 \text { and } \overline{\mathrm{LB}} \text { input. In the case of input } 12 \text { (Ay) this data is valid for two cycles because } \overline{\mathrm{ADV}} \text { is high and has suspended the burst. }}{\text { and }}$
3. CSo timing transitions are identical but inverted to the $\overline{\mathrm{CE}}$ and $\overline{\mathrm{C}} 1$ signals. For example, when $\overline{\mathrm{C}} \overline{\mathrm{E}}$ and $\overline{\mathrm{C}} \overline{\mathrm{S}} 1$ are LOW on this waveform, CS 0 is HIGH .

Timing Waveform of Write Cycle No. 2 - Byte Controlled ${ }^{(1,2,3)}$


NOTES:

1. ZZ input is LOW, $\overline{\overline{W W}}$ is HIGH and $\overline{\mathrm{LBO}}$ is Don't Care for this cycle.
2. $04(\mathrm{Aw})$ represents the final output data in the burst sequence of the base address Aw. I1 (Ax) represents the first input from the external address Ax. I1 (Ay) represents the first input from the external $\frac{a d d r e s s ~}{A y}$; 12 (Ay) represents the next input data in the burst sequence of the base address $A y$, etc. where $A 0$ and $A 1$ are advancing for the four word burst in the sequence defined by the state of the $\overline{\mathrm{LBO}}$ input. In the case of input I 2 (Ay) this data is valid for two cycles because $\overline{\mathrm{ADV}}$ is high and has suspended the burst.
CSo timing transitions are identical but inverted to the $\overline{\mathrm{CE}}$ and $\overline{\mathrm{CS}} 1$ signals. For example, when $\overline{\mathrm{CE}}$ and $\overline{\mathrm{C}} 1$ are LOW on this

Timing Waveform of Sleep（ZZ）and Power－Down Modes ${ }^{(1,2,3)}$

|  | $\square_{\text {ss }}$ |  |  |  |  |  |  |  |  | $\checkmark$ | 1 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | ］${ }^{185}$ | एY | XV | 观 | EXY | एY | एY | ए $\times$ |  | ， | EY |
| Dosc | XXY XX | XY XVY | XY | V | एXY | XY | XY | XY | XY |  | XY |
| ${ }_{\text {adoress }}$ | XXXXXX＊${ }^{-1}$ | Etxay | XXXXXY | 8xx | xxyxxyxx | \xxyxx | kxyxy | yxxyxx | 奴 | \％X 8 \％ | y $x$ XXXXX |
| ${ }^{\text {aw }}$ | XY XXY W | XY XXY | XY | V | एVY | XY | WY | एY | XY | XYY | VY |
|  |  | $\frac{100}{x \times x \times X X X}$ | Lux | 双 | XXXXXXX | W8x | W8x8 | max | NXXX | \％ | ए $\times 1+1 \times$ |
|  |  |  | X $\times$ XXXX | XXX | XxXXXXXX | XXXXX | XXXXXX | XXXXX | XXXXXX | XXXXXX | \XXXXXXX |
|  |  |  |  |  |  |  |  |  |  |  |  |
|  | － |  |  |  |  |  |  |  |  |  |  |
|  |  | amply |  |  |  |  |  |  |  |  |  |
|  |  |  |  |  |  |  |  |  |  |  |  |
|  |  |  |  |  |  |  |  |  |  |  |  |

[^0]
## Non-Burst Read Cycle Timing Waveform



NOTES:

1. ZZ input is LOW, $\overline{\mathrm{ADV}}$ is HIGH and $\overline{\mathrm{LBO}}$ is Don't Care for this cycle.
2. (Ax) represents the data for address $A x$, etc.
3. For read cycles, $\overline{\mathrm{ADSP}}$ and $\overline{\mathrm{ADSC}}$ function identically and are therefore interchangable.

## Non-Burst Write Cycle Timing Waveform



NOTES:

1. ZZ input is LOW, $\overline{\mathrm{ADV}}$ and $\overline{\mathrm{OE}}$ are HIGH, and $\overline{\mathrm{LBO}}$ is Don't Care for this cycle.
2. (Ax) represents the data for address $A x$, etc.
3. Although only $\overline{\mathrm{GW}}$ writes are shown, the functionality of $\overline{\mathrm{BWE}}$ and $\overline{\mathrm{BW}} x$ together is the same as $\overline{\mathrm{GW}}$.
4. For write cycles, $\overline{\mathrm{ADSP}}$ and $\overline{\mathrm{ADSC}}$ have different limitations.

JTAG Interface Specification (SA Version only)


NOTES:

1. Device inputs = All device inputs except TDI, TMS and TRST.
2. Device outputs = All device outputs except TDO.
3. During power up, $\overline{\text { TRST }}$ could be driven low or not be used since the JTAG circuit resets automatically. $\overline{\text { TRST }}$ is an optional JTAG reset.

JTAG AC Electrical
Characteristics ${ }^{(1,2,3,4)}$

| Symbol |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
|  | Parameter | Min. | Max. | Units |
|  | JTAG Clock Input Period | 100 | - | ns |
| tJCH | JTAG Clock HIGH | 40 | - | ns |
| tJCL | JTAG Clock Low | 40 | - | ns |
| tRR | JTAG Clock Rise Time | - | $5^{(1)}$ | ns |
| tJF | JTAG Clock Fall Time | - | $5^{(1)}$ | ns |
| tJRST | JTAG Reset | 50 | - | ns |
| tJRSR | JTAG Reset Recovery | 50 | - | ns |
| tJCD | JTAG Data Output | - | 20 | ns |
| tJDC | JTAG Data Output Hold | 0 | - | ns |
| tJS | JTAG Setup | 25 | - | ns |
| tJH | JTAG Hold | 25 | - | ns |

## Scan Register Sizes

| Register Name | Bit Size |
| :--- | :---: |
| Instruction (IR) | 4 |
| Bypass (BYR) | 1 |
| JTAG Identification (JIDR) | 32 |
| Boundary Scan (BSR) | Note (1) |

NOTE:

1. The Boundary Scan Descriptive Language (BSDL) file for this device is available

## NOTES:

1. Guaranteed by design.
2. AC Test Load (Fig. 1) on external output signals.
3. Refer to AC Test Conditions stated earlier in this document.
4. JTAG operations occur at one speed (10MHz). The base device may run at any speed specified in this datasheet.

## JTAG Identification Register Definitions (SA Version only)

| Instruction Field | Value | Description |
| :--- | :---: | :--- |
| Revision Number (31:28) | $0 \times 2$ | Reserved for version number. |
| Device ID (27:12) | $0 \times 22 C, 0 \times 22 E$ | Defines AS8C403625/1825 |
| JEDEC ID (11:1) | $0 \times 33$ | Allows unique identification of device vendor. |
| ID Register Indicator Bit (Bit 0 ) | 1 | Indicates the presence of an ID register. |

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## Available JTAG Instructions

| Instruction | Description | OPCODE |
| :---: | :---: | :---: |
| EXTEST | Forces contents of the boundary scan cells onto the device outputs ${ }^{(1)}$. Places the boundary scan register (BSR) between TDI and TDO. | 0000 |
| SAMPLE/PRELOAD | Places the boundary scan register (BSR) between TDI and TDO. SAMPLE allows data from device inputs ${ }^{(2)}$ and outputs ${ }^{(1)}$ to be captured in the boundary scan cells and shifted serially through TDO. PRELOAD allows data to be input serially into the boundary scan cells via the TDI. | 0001 |
| DEVICE_ID | Loads the JTAG ID register (JIDR) with the vendor ID code and places the register between TDI and TDO. | 0010 |
| HIGHZ | Places the bypass register (BYR) between TDI and TDO. Forces all device output drivers to a High-Z state. | 0011 |
| RESERVED | Several combinations are reserved. Do not use codes other than those identified for EXTEST, SAMPLE/PRELOAD, DEVICE_ID, HIGHZ, CLAMP, VALIDATE and BYPASS instructions. | 0100 |
| RESERVED |  | 0101 |
| RESERVED |  | 0110 |
| RESERVED |  | 0111 |
| CLAMP | Uses BYR. Forces contents of the boundary scan cells onto the device outputs. Places the bypass register (BYR) between TDI and TDO. | 1000 |
| RESERVED | Same as above. | 1001 |
| RESERVED |  | 1010 |
| RESERVED |  | 1011 |
| RESERVED |  | 1100 |
| VALIDATE | Automatically loaded into the instruction register whenever the TAP controller passes through the CAPTURE-IR state. The lower two bits '01' are mand ated by the IEEE std. 1149.1 specification. | 1101 |
| RESERVED | Same as above. | 1110 |
| BYPASS | The BYPASS instruction is used to truncate the boundary scan register as a single bit in length. | 1111 |

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NOTES:

1. Device outputs = All device outputs except TDO.
2. Device inputs = All device inputs except TDI, TMS, and $\overline{\text { TRST }}$.

ORDERING INFORMATION

| Alliance | Organization | VCC <br> Range | Package | Operating Temp | Speed <br> ns |
| :---: | :---: | :---: | :---: | :---: | :---: |
| AS8C403625-QC75N | $256 \mathrm{~K} \times 36$ | $3.1-3.4 \mathrm{~V}$ | 100 pin TQFP | Comercial $0-70 \mathrm{C}$ | 7.5 |
| AS8C401825-QC75N | $512 \mathrm{~K} \times 18$ | $3.1-3.4 \mathrm{~V}$ | 100 pin TQFP | Comercial $0-70 \mathrm{C}$ | 7.5 |

## PART NUMBERING SYSTEM

| AS8C | Device | Conf. | Mode | Package | Operating Temp | Speed | N |
| :---: | :---: | :--- | :---: | :---: | :---: | :---: | :---: |
| Sync. <br> SRAM prefix | $40=4 \mathrm{M}$ | $18=x 18$ <br> $36=x 36$ | $01=$ ZBT <br> $00=$ Pipelined <br> $25=$ Flow- Thru | Q=100 Pin TQFP | $0 \sim 70 \mathrm{C}$ | 7.5 ns | N= Leadfree |

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[^0]:    NOTES：
    1．Device must power up in deselected Mode．
    2．$\overline{\mathrm{LBO}}$ is Don＇t Care for this cycle．
    3．It is not necessary to retain the state of the input registers throughout the Power－down cycle．
    4．CSo timing transitions are identical but inverted to the $\overline{\mathrm{C}} \overline{\mathrm{E}}$ and $\overline{\mathrm{CS}} 1$ signaals．For example，when CE and CS1 are LOW on this waveform， CS 0 is HIGH ．

